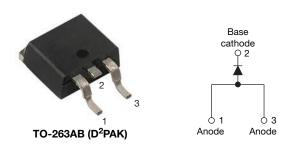


VS-20ETS08SPbF, VS-20ETS12SPbF

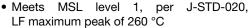
Vishay Semiconductors

High Voltage Surface Mount Input Rectifier Diode, 20 A

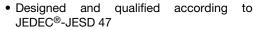


PRODUCT SUMMARY						
Package	TO-263AB (D ² PAK)					
I _{F(AV)}	20 A					
V_{R}	800 V, 1200 V					
V _F at I _F	1.1 V					
I _{FSM}	300 A					
T _J max.	150 °C					
Diode variation	Single die					

FEATURES







 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

- · Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-20ETS...SPbF rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS					
Capacitive input filter T _A = 55 °C, T _J = 125 °C common heatsink of 1 °C/W	16.3	21	А					

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Sinusoidal waveform	20	A						
V _{RRM}		800/1200	V						
I _{FSM}		300	A						
V _F	20 A, T _J = 25 °C	1.1	V						
TJ		-40 to +150	°C						

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA						
VS-20ETS08SPbF	800	900	1						
VS-20ETS12SPbF	1200	1300	ı						



VS-20ETS08SPbF, VS-20ETS12SPbF

Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	$T_C = 105$ °C, 180° conduction half sine wave	20					
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated V _{RRM} applied	250	А				
	IFSM	10 ms sine pulse, no voltage reapplied	300					
Maying up 12t fay fuaing	l ² t	10 ms sine pulse, rated V _{RRM} applied	316	A ² s				
Maximum I ² t for fusing	1-1	10 ms sine pulse, no voltage reapplied		A-S				
Maximum I²√t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s				

ELECTRICAL SPECIFICATIONS								
PARAMETER SYMBOL TEST CONDITIONS					UNITS			
Maximum forward voltage drop	V_{FM}	20 A, T _J = 25 °C	1.1	V				
Forward slope resistance	r _t	T _{.1} = 150 °C	10.4	mΩ				
Threshold voltage	V _{F(TO)}	1j = 150 C	0.85	V				
Maximum reverse leakage current		T _J = 25 °C	V - Potod V	0.1	mΛ			
Maximum reverse leakage current	IRM	T _J = 150 °C	V_R = Rated V_{RRM}	1.0	mA			

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		- 40 to 150	°C			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.3				
Maximum thermal resistance, junction to ambient		R _{thJA} ⁽¹⁾	For D ² PAK version	62	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5				
Approximate weight				2	g			
Approximate weight				0.07	OZ.			
minimum				6.0 (5.0)	kgf · cm			
Mounting torque -	maximum			12 (10)	(lbf \cdot in)			
Marking device			Consisted TO 262AB (D2BAK)	20ETS08S				
			Case style TO-263AB (D ² PAK)	20ETS12S				

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994



www.vishay.com

Vishay Semiconductors

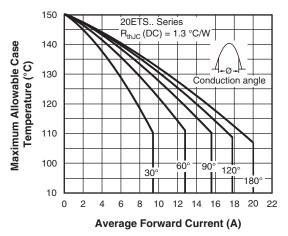


Fig. 1 - Current Rating Characteristics

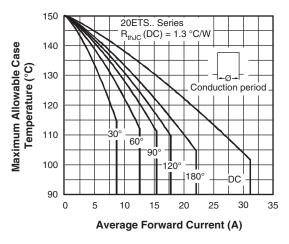


Fig. 2 - Current Rating Characteristics

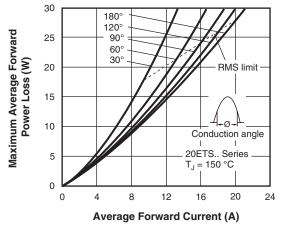


Fig. 3 - Forward Power Loss Characteristics

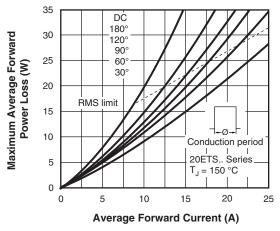


Fig. 4 - Forward Power Loss Characteristics

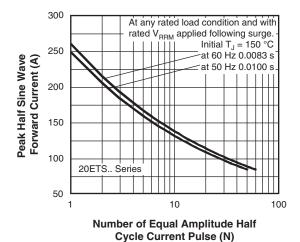


Fig. 5 - Maximum Non-Repetitive Surge Current

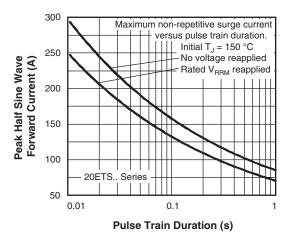


Fig. 6 - Maximum Non-Repetitive Surge Current



Vishay Semiconductors

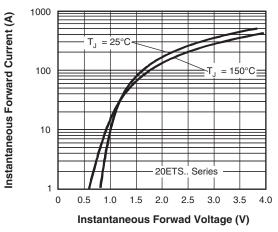


Fig. 7 - Forward Voltage Drop Characteristics

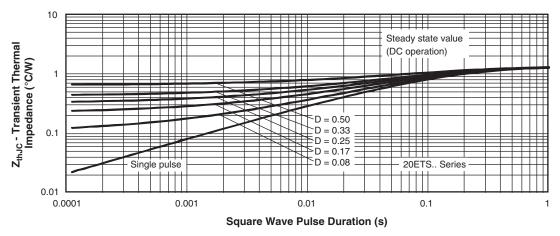


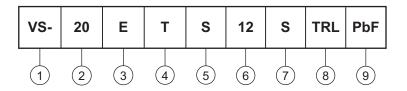
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

VS-20ETS08SPbF, VS-20ETS12SPbF

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- Current rating (20 = 20 A)

3 - Circuit configuration

E = single diode

4 - Package:

T = TO-220AC

5 - Type of silicon:

S = standard recovery rectifier

- Voltage code x 100 = V_{RRM} - 08 = 800 V 12 = 1200 V

7 - S = TO-220 D²PAK (SMD-220) version

8 - • None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

9 - PbF = Lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-20ETS08SPbF	50	1000	Antistatic plastic tube						
VS-20ETS08STRRPbF	800	800	13" diameter reel						
VS-20ETS08STRLPbF	800	800	13" diameter reel						
VS-20ETS12SPbF	50	1000	Antistatic plastic tube						
VS-20ETS12STRRPbF	800	800	13" diameter reel						
VS-20ETS12STRLPbF	800	800	13" diameter reel						

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?9504						
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					
SPICE model	www.vishay.com/doc?95409					



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		LLIMETERS INCHES		NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

Legal Disclaimer Notice



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.